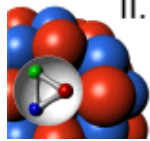
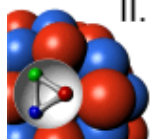


Barrel Strip Sensors Production Batch Testing



Production Batch

- Ordered 4 Lots with 25 wafer each end of 2014
- Based on 400 wafers ordered with specific resistivity ($3 \text{ k}\Omega\text{cm}$)
- 3 Lots delivered so far
 - Post production tests at CiS according to:
 - IV-curve
 - pin-holes
 - breakdown voltage
 - Only sensors that passed the tests are delivered to Giessen
 - So far: low yield

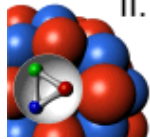


Production Batch

- Yield overview

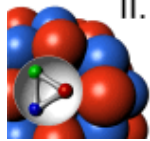
Lot	b65 (S1)	m65 (S2)
341774	20 %	40 %
341775	4 %	8 %
341776	28 %	36 %
total	17.3 %	28 %

- Reasons for exclusion/failed test
 - pin-hole excluded - 35 %
 - IV, breakdown excluded - 33 %
- Problem with process at CiS
- Also reported by CBM (J. Heuser)



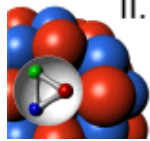
Production Batch Testing

- Tests of delivered sensors in Giessen
- m65 (S2) sensors tested
 - Probe station
 - 2 sensors of lot 341774
 - 1 sensor of lot 341775
 - 2 sensors of lot 341776
 - Probe card
 - one sensor from probe station test for each lot

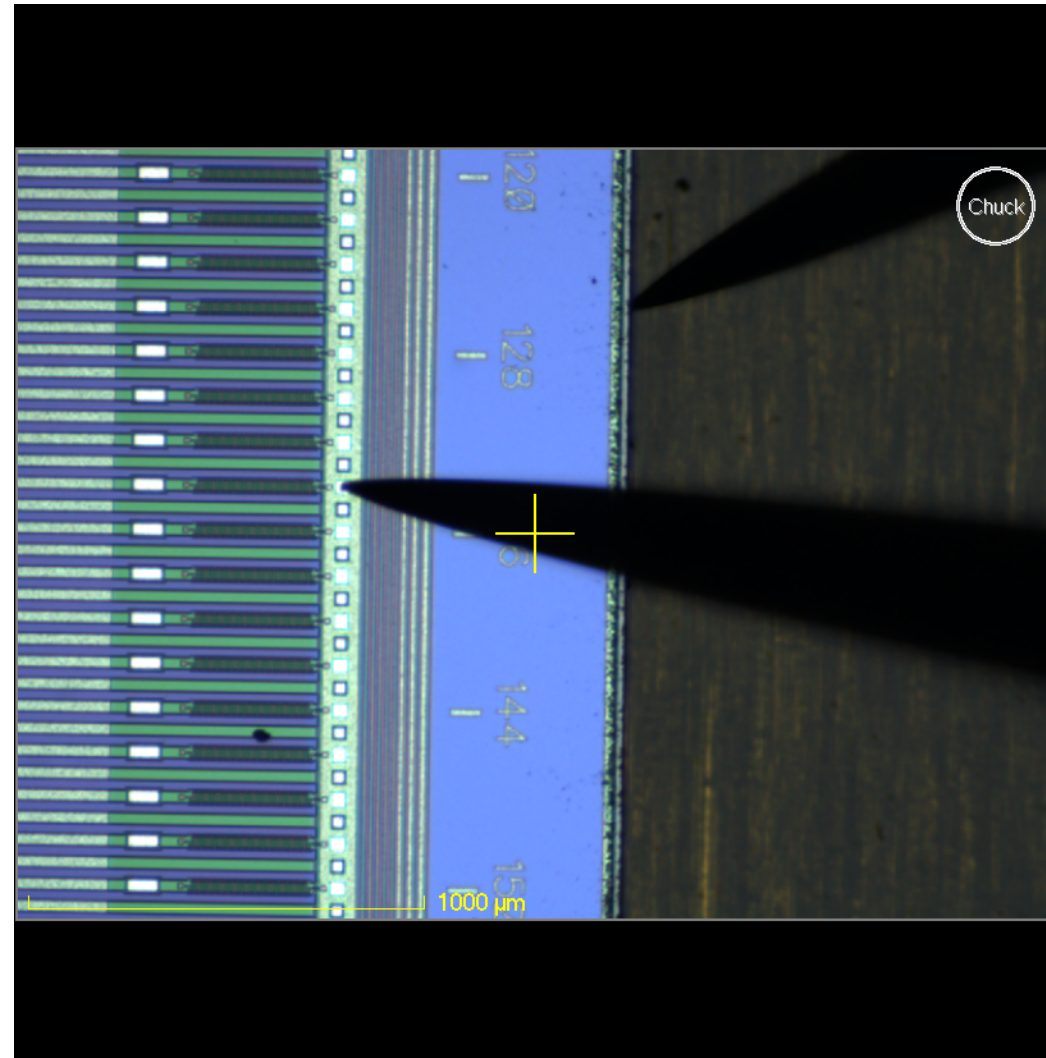
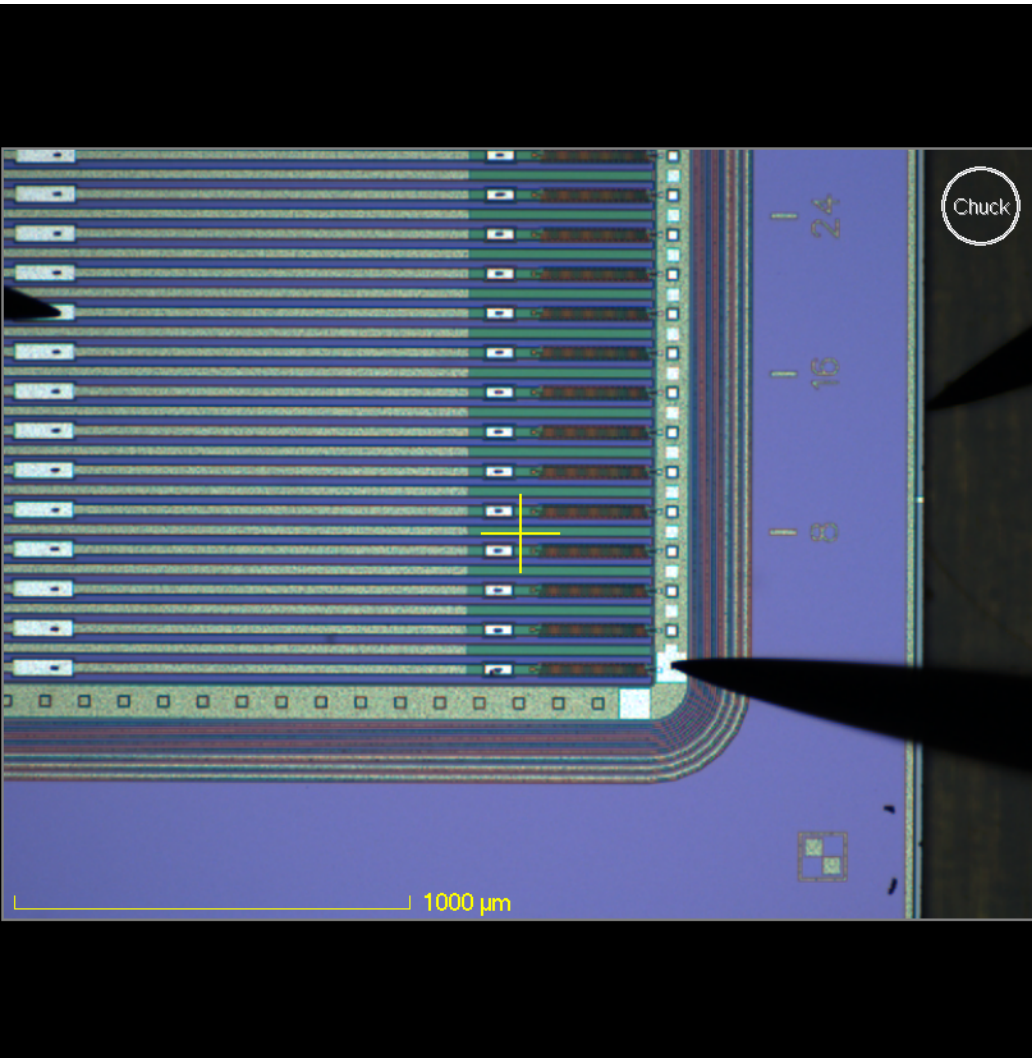


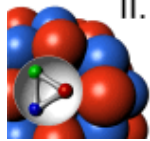
Probe Station Tests

- Limited testing capability (only one sensor side)
 - Setup
 - biasing: 2 needles via p-side bias ring and sensor edge (bulk)
 - LCR: 1 kelvin probe on AC-pad to chuck
 - kapton tape between sensor and chuck
 - Measurements
 - IV
 - CV
 - 6 strips per sensor (only p-side)
 - Advantage
 - fast screening possible
 - precise values (calibration)
 - Disadvantage
 - no realistic measurement case (strip to chuck)



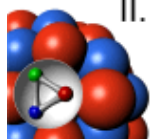
Probe Station Setup





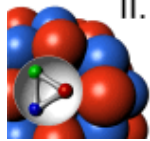
Probe Card Tests

- High testing capability (both sensor sides)
 - Strips bonded to probe card
 - p- and n-side
 - common line and some individual strips
 - AC-pads and DC-pads
 - Every second strips bonded
 - floating strip like in final detector
 - Possibility to "cancel out" structures
 - Advantage
 - realistic measurement case
 - Disadvantage
 - unknown offset (PCB trace from pin-header to bond pad)



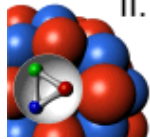
Probe Card Setup





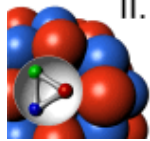
Probe Station Results

- Primary to compare with CiS measurements
 - Depletion voltage
 - $3 \text{ k}\Omega\text{cm} \pm 10\%$ relates to 82...107 V
 - agreement with CiS within $\pm 10\%$
 - Leakage current
 - consider different temperatures of measurements
 - within $\pm 10\%$
 - Breakdown voltage
 - to occur systemically earlier (e.g. 320V instead of 460V)
 - Single strip to chuck capacity
 - value comparable to probe card measurement for c_b



Probe Card Results

- Extract values that are not accessible via probe station
 - Like
 - entire p-side to entire n-side → C_b
 - single strip one side to entire opposite side
 - entire side to biasring → stray capacity
 - n-side
 - Capacity values from measurements on the following slides



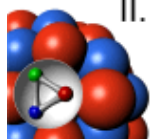
Sensor Capacities

$$C_{\text{tot}} = C_b + C_{\text{is}} + C_s$$

c_b body capacity

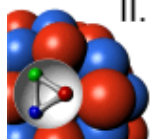
c_{is} interstrip capacity

$c_s = c_{s,p} + c_{s,n}$ stray capacity



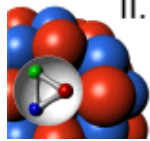
Sensor Capacities - c_b

	100kHz	1MHz
C_b	291.7 ± 7.9	358.1 ± 10.2
c_b	1.14 ± 0.03	1.40 ± 0.04
c_b P1	1.37 ± 0.10	2.61 ± 0.24
c_b P2	1.18 ± 0.12	2.26 ± 0.22
c_b P3	1.25 ± 0.12	2.31 ± 0.26
c_b P4	1.28 ± 0.09	2.27 ± 0.24
c_b P5	1.13 ± 0.10	2.32 ± 0.26
c_b N1	1.40 ± 0.05	0.63 ± 0.13



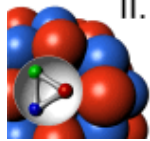
Sensor Capacities - c_{is}

	100kHz	1MHz
c_{is} P1	4.62 ± 0.33	5.09 ± 0.47
c_{is} P2	5.66 ± 0.34	6.29 ± 0.49
c_{is} P3	5.24 ± 0.29	6.47 ± 0.47
c_{is} P4	4.93 ± 0.26	6.09 ± 0.44
c_{is} P5	4.27 ± 0.26	5.41 ± 0.43
c_{is} N1	7.70 ± 1.65	12.2 ± 1.6



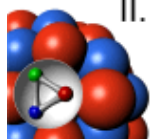
Sensor Capacities - c_s

	100kHz	1MHz
ComP to p-bias per p-strip	9.5±10.5 0.04±0.04	122.79±11.7 0.48±0.05
ComP to n-bias per p-strip	24.3±3.5 0.10±0.01	9.33±2.16 0.04±0.01
ComN to p-bias per n-strip	9.5±10.5 0.04±0.04	125.8±8.8 0.49±0.03
ComN to n-bias per n-strip	451.5±9.2 1.76±0.04	122.1±10.5 0.48±0.04



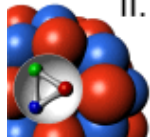
Sensor Capacities - c_{tot}

	100kHz	1MHz
ComP per strip	6.15 ± 0.38	7.79 ± 0.56
c_{tot} P1	6.33 ± 1.83	8.76 ± 1.12
c_{tot} P2	6.98 ± 0.51	9.07 ± 0.77 (c_s from ComP)
c_{tot} P3	6.63 ± 0.46	9.30 ± 0.79 (c_s from ComP)
c_{tot} P4	6.59 ± 1.13	9.49 ± 1.84
c_{tot} P5	5.88 ± 1.04	8.75 ± 1.34
ComN per strip	10.64 ± 1.76	14.57 ± 1.71
c_{tot} N1	11.99 ± 2.25	14.33 ± 3.06



Sensor Capacities - c_{tot}

		100kHz	1MHz
m65 (S2) (3.5x3.5 cm ²)	p-side	6.15±0.38	7.79±0.56
	n-side	10.64±1.76	14.57±1.71
b65 (S1) (3.5x6.0 cm ²)	p-side	6.15±0.38	7.79±0.56
	n-side	18.60±3.10	25.50±3.00



Thank you for your Attention

